

Revision 1.00

Absolute Maximum Ratings

TAPERED AMPLIFIERS Semiconductor Optical Amplifier



General Product Information	
Product	Application
970 nm Tapered Amplifier	Spectroscopy
Gain from 950 nm to 980 nm (see p. 2)	Metrology
C-Mount Package	



Parameter	Symbol	Unit	min	typ	max
Storage Temperature	T _S	°C	-40		85
Operational Temperature at Case	T_C	°C	0		50
Forward Current	I _F	А			4.5
Reverse Voltage	V_R	V			2
Output Power	P _{opt}	W			3.0

Measurement Conditions / Comments
Stress in excess of one of the Absolute Maximum
Ratings may damage the laser. Please note that a
damaging optical power level may occur although the
maximum current is not reached. These are stress
ratings only, and functional operation at these or any
other conditions beyond those indicated under
Recommended Operational Conditions is not implied.

Parameter	Symbol	Unit	min	typ	max
Operational Temperature at Case	T _C	°C	5		40
Forward Current	I _F	А			4.0
Input Power	P _{input}	mW	10		50
Output Power	P _{opt}	W			3.0

Measurement Conditions / Comments
non condensing
operation without seeding not recommended
with proper injection from a seed laser

Parameter	Symbol	Unit	min	typ	max
Wavelength	λ_{C}	nm		970	
Gain Width (FWHM)	Δλ	nm		30	
Temp. Coefficient of Wavelength	dλ / dT	nm / K		0.3	
Output Power	P _{opt}	W		2.5	
Amplification	G	dB		21	
Cavity length	L _C	μm		4000	

= 25 °C at BOL

maximun	ı gain			
see Typic	al Measurer	nent Resul	ts (p. 2)	
at maxim	um gain			
with prop	er injection	from a see	d laser	

Characteristics at T_{LD}



Revision 1.00

TAPERED AMPLIFIERS Semiconductor Optical Amplifier

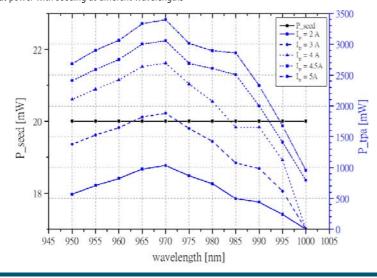


Characteristics at T _{LD} = 25	5 °C at BOL				cont'd
Parameter	Symbol	Unit	min	typ	max
Reflectivity at Front Facet	R_{ff}			3·10-4	1.10-3
Reflectivity at Rear Facet	R_{rf}			3·10-4	1.10-3
Input Aperture (at rear side)	d _{in}	μm		2.4	
Output Aperture (at front side)	d_{out}	μm		210	
Astigmatism	А	μm		700	
Input Divergence parallel	$\Theta_{in }$	0		24	
Input Divergence perpendicular	$\Theta_{in\perp}$	0		37	
Output Divergence parallel	$\Theta_{out }$	0		18	
Output Divergence perpendicular	$\Theta_{out\perp}$	0		37	
Polarization				TE	

Measurement Conditions / Comments
at recommended maximum forward current
1/e2
1/e2
1/e2
1/e2
E field parallel to junction plane

Typical Measurement Results

output power with seeding at different wavelengths



Graphs, data and any illustrative material provided in this specification describe the typical performance of the tapered amplifier. The achievable amplification depends strongly on a proper injection of the seed laser. In accordance with the eagleyard Photonics policy of continuous improvement specifications may change without notice.



Revision 1.00

TAPERED AMPLIFIERS Semiconductor Optical Amplifier

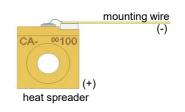


Package Dimensions					
Parameter	Symbol	Unit	min	typ	max
Height of Emission Plane	h	mm	7.5	7.10	20.7
C-Mount Thickness	t	mm		4.5	

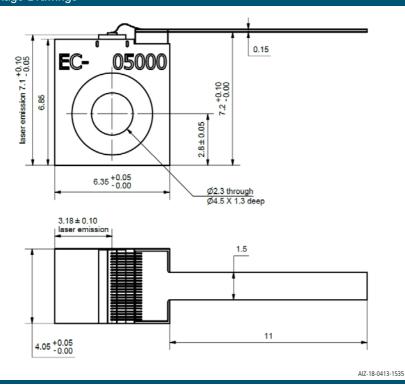
Measurement Conditions / Comments		

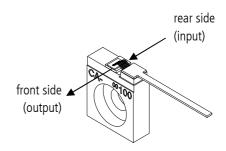
Package Pinout

Mounting Wire	Cathode (-)
Housing	Anode (+)



Package Drawings





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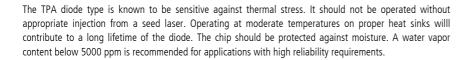
Revision 1.00

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Unpacking, Installation and Laser Safety

Unpacking the laser diodes should only be done at electrostatic safe workstations (EPA). Though protection against electro static discharge (ESD) is implemented in the laser package, charges may occur at surfaces. Please store this product in its original package at a dry, clean place until final use. During device installation, ESD protection has to be maintained.



The laser emission from this diode is close to the invisible infrared region of the electromagnetic spectrum. Avoid direct and/or indirect exposure to the free running beam. Collimating the free running beam with optics as common in optical instruments will increase threat to the human eye.

Each tapered amplifier will come with an individual test protocol verifying the parameters given in this document.

